

Sematech

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TABLE OF CONTENTS

Volume 1 Oral Sessions

Symposium Opening Address	1
<i>Rob Hartman</i>	
Nikon EUVL development progress update	43
<i>Takaharu Miura</i>	
Canon's Development Status of EUVL Technologies	72
<i>Shigeyuki Uzawa</i>	
Progress on the Realization of EUV Lithography	93
<i>Hans Meiling</i>	
Full-field imaging by the ASML EUV Demo Tool	N/A
<i>Rogier Groeneveld</i>	
Baselining the performance of a EUVL full field scanner through rigorous modeling	121
<i>Frank Goodwin</i>	
Requirements and prospects of next generation Extreme Ultraviolet Sources for Lithography Applications	141
<i>V.Y. Banine</i>	
Development of EUV sources with tin fuel and rotating disk electrodes	169
<i>Vladimir Borisov</i>	
Collector optics integration into medium power EUV source systems	183
<i>Giovanni Bianucci</i>	
Asia Pacific Regional Update	198
<i>Ichiro Mori Selete</i>	
Summary of Japanese academic support program for EUVL source	210
<i>Yasukazu Izawa</i>	
Extending the lifetime of collector optics: advanced debris mitigation schemes and cleaning methods	231
<i>David Ruzic</i>	
Table-Top EUV lasers for Metology	275
<i>Jorge Rocca</i>	
Investigation of lithographic metrics for the characterization of intrinsic resolution limits in EUV resists	302
<i>Patrick Naulleau</i>	
Performance of new molecular resist in EUV lithography	326
<i>Hiroaki Oizumi</i>	
Single component molecular glass resists for EUVL	343
<i>Clifford Henderson</i>	

Quantitative measurement of EUV resist outgassing	372
<i>Gregory Denbeaux</i>	
The design of chemically amplified resist for EUV lithography	392
<i>Hiroto Yukawa</i>	
Smoothing EUVL mask substrate defects with an emphasis on real-world pits	408
<i>Paul Mirkarimi</i>	
Challenges of removing sub 40 particles in EUV mask blank cleaning	426
<i>Abbas Rastegar</i>	
Removal of nano-particles on EUV mask buffer and absorber layers by laser shockwave cleaning	454
<i>Young-Sam Yu</i>	
The repair performance comparison for EUV mask	476
<i>Moon Gyu Sung</i>	
Impact of 3-D mask effects on CD and overlay over image field in Extreme Ultraviolet Lithography	494
<i>Sven Trogisch</i>	
Symposium Keynote Speaker	515
<i>Martin Van den Brink</i>	
High power EUV source development for beta-level and high volume manufacturing lithography	562
<i>Uwe Stamm</i>	

Volume 2

The Philips Extreme UV Source: recent progress in power, lifetime and collector lifetime	592
<i>Marc Corthout</i>	
Development of high-power Sn-fueled DPP EUV source for enabling HVM	610
<i>Yusuke Termoto</i>	
LPP source development for HVM EUV lithography	626
<i>David Brandt</i>	
Development status of HVM laser produced plasma EUV light source	649
<i>Akira Endo</i>	
European Regional Update	668
<i>Rob Hartman</i>	
Optics for EUV Lithography	679
<i>Peter Kuerz</i>	
Development of beta EUV mask blanks at Hoya	697
<i>Takeyuki Yamada</i>	
Current status of EUVL mask blank coating development in AGC	714
<i>Takashi Sugiyama</i>	
Defect Mitigation and Reduction in EUVL mask blanks	734
<i>Patrick Kearney</i>	
The study for image placement accuracy of EUV mask on the flat chuck	750
<i>Shusuke Yoshitake</i>	
Plenary Talk: International EUV Initiative	771
<i>Paolo Gargini</i>	

EUV Resist materials properties and performance	811
<i>Michael Leeson</i>	
EUV Resist material study for the outgassing reduction and LWR improvement.....	834
<i>Seiya Masuda</i>	
Novel CA resist system for EUVL.....	856
<i>Takeo Watanabe</i>	
Improved EUV photoresist performance through processing refinements	881
<i>Thomas Wallow</i>	
EUV resist performance under high stray light levels: an interference lithography study.....	903
<i>Roel Gronheid</i>	
Accuracy of the ASET Dilatometer for low thermal expansion materials	926
<i>Yoshimasa Takeichi</i>	
Line edge roughness and cross sectional characterization of sub-50nm structures using CD-SAXS.....	950
<i>Ronald Jone</i>	
Development of EUV wavefront metrology systems (EWMS)	970
<i>Katsuhiko Murakami</i>	
Towards an Affordable Cost of Ownership	994
<i>Melissa Shell</i>	
United States Regional Update.....	1018
<i>Stefan Wurm</i>	
Contamination cleaning of Ru-capped EUV multilayer-mirror with atomic hydrogen.....	1029
<i>Iwao Nishiyama</i>	
Essential procedures for endurance testing of multi-layer mirrors	1049
<i>Shannon Hill</i>	
Radiation-induced processes on Ru surfaces: relevance to EUVL.....	1091
<i>Theodore Madey</i>	
Carbon deposition on multi-layer mirrors by extreme ultra violet ray irradiation	1109
<i>Takashi Aoki</i>	
Mo/Si multilayers capped by TiO₂.....	1123
<i>Sergiy Yulin</i>	
Comparison of actinic and non-actinic inspection of programmed-defect masks.....	1143
<i>Kenneth Goldberg</i>	

Volume 3

State of the art EUV mask blank inspection with a Lasertec M7360 at the SEMATECH MBDC	1191
<i>Patrick Kearney</i>	
Development of EUV pellicle for reticle defect mitigation	1207
<i>Yashesh Shroff</i>	
EUVL Mask Carrier Development.....	1236
<i>David Halbmeier</i>	
Status and path to particle-free EUVL reticle protection solution	1264
<i>Long He</i>	

2006 EUVL Symposium Closing Address	1278
<i>Rob Hartman</i>	

Poster Sessions

Comparison of Extreme Ultra-Violet Interference Lithography Optical Designs for Photoresist Research	1323
<i>Michael Goldstein</i>	
First EUV Contact Lithography Experiments for the Coloration of Lithium Fluoride	1338
<i>Francesco Flora</i>	
The Italian National FIRB Project on EUV Lithography.....	1357
<i>A. Reale-d</i>	
Study on Photo-Chemical Analysis System for EUV Lithography	1386
<i>A.Sekiguchi</i>	
Design for a Stand-Alone Extreme Ultraviolet Interference Lithography Tool.....	1402
<i>Patrick Naulleau</i>	
Low-Debris, EUV Source Using a Colloidal Microjet Target Containing Tin Dioxide Nanoparticles	1403
<i>Shoichi Kubodera</i>	
Optimization of 13.5 nm Conversion Efficiencies for LPP and DPP EUVL Radiation Sources.....	1428
<i>Joseph J. MacFarlane</i>	
Development of a Gas Jet-Type Z Pinch EUV Light Source for Lithography	1454
<i>Naoya Iizuka</i>	
Laser and Target Optimization for the Highest Conversion to 13.5 nm EUV Light with Laser Produced, Minimum-Mass Tin Plasma	1455
<i>Hiroaki Nishimura</i>	
Modeling of the Atomic Processes in EUVL Source Plasmas	1465
<i>Akira. Sasaki</i>	
RZLine MHD Model of Z-Pinch Discharge Based EUV Source	1467
<i>V. Ivanov</i>	
Characterization of Debris Mitigation Techniques for a Sn and Ze-fueled DPP EUV Light Source	1482
<i>Keith Thompson</i>	
Temperature and Density Measurement of Laser-Produced EUV Plasmas	1483
<i>Tatsuya Aota</i>	
Emission Characteristics of Neutral Atoms and Ions of Laser-Produced Tin Plasma.....	1496
<i>Akihiko Takahashi</i>	
EUV Emission Spectra of Charge-Selected Sn Ions in Charge Exchange Spectroscopy	1515
<i>Hajime Tanuma</i>	
Development of High-peak, High-Average LD Pumped Solid-State Laser System for EUV Generation.....	1516
<i>Koji Tsubakimoto</i>	
LPP-EUV Sources Using Cryogenic Xe and Lithium New Scheme Targets	1531
<i>Sho Amano</i>	

Development of Low-Density Target for High Efficient EUV Generation	1551
<i>Keiji Nagai</i>	
Theoretical Guidelines of LPP-EUV Sources for HVM	1577
<i>Katsunobu Nishihara</i>	
Analysis of the Effects of a Small Area Magnetic Field for the Mitigation of the Debris Emitted by a Laser Plasma Source	1578
<i>Daniel Amodio</i>	
Industrial Kilowatt-Class Laser Modules in Scaling Up Laser Produced Plasmas (LPP) EUV Source	1593
<i>Samir Ellwi</i>	
Latest Development of EUV-Sources for Flexible Laboratory Use	1607
<i>Rainer Lebert</i>	
Characterization of Ionic Debris Interaction with a Buffer Gas in the Frame of Debris Mitigation Issues	1617
<i>Sarah Bollanti</i>	
Systematics of Atomic 4d-4f Transitions of Atomic Ions in EUVL Source Plasmas and Neighboring Atomic Numbers	1642
<i>Fumihiko Koike</i>	
In-situ EUV reflectivity of Ru, Pd and Rh single-layer mirrors exposed to energetic and thermal Sn	1664
<i>J.P. Allain</i>	
LPP Source System Development Results	1665
<i>Igor V. Fomenkov</i>	
Potentiality of Magnetically Confined Plasma as an Efficient Extreme Ultraviolet Source	1680
<i>Kazuhiko Horioka</i>	
Radiation Hydrodynamic Simulation for LPP EUV Sources	N/A
<i>Atsushi Sunahara</i>	
Tin Material Consumption and the Mirror Lifetime for Droplet Laser Plasma Sources	1698
<i>Kazutoshi Takenoshita</i>	
Toward HVM Conditions with the Tin-Doped Droplet Laser Plasma Source	1699
<i>M. Richardson</i>	
Mitigation Schemes for the Tin-Doped Droplet Target	1700
<i>Tobias Schmid</i>	
Out-of-Band Spectroscopy of the Tin Droplet Target	1701
<i>Simi A. George</i>	
Microdischarge Array for Advanced EUVL Illumination	1702
<i>Brian E. Jurczyk</i>	
One Watt EUV Production by 80cm Outer Diameter Tabletop Synchrotron MIORCLE-20SX	1703
<i>Hironari Yamada</i>	
EUV Source Development Using High-Current Pulsed Power Generator	N/A
<i>Nobuaki Oshima</i>	

Angle-Resolved Absolute Out-of-Band Radiation Studies of Tin-Based LPP Sources	N/A
<i>O. Morris</i>	
Axial Dynamics of Z-pinch Plasmas Driven by 100 ns-Long Current Pulses	1705
<i>Sunao Katsuki</i>	
Sn Cleaning of Multi-Layer Mirrors with Hydrogen Radicals	1706
<i>Maarten van Herpen</i>	
Present Status of Laser-Produced Plasma EUV Light Source	1707
<i>Akira Endo</i>	
Small Field Exposure Tool (SFET) Light Source Status	1708
<i>Tamotsu Abe</i>	
Calculation of Sn and Xe Emission Spectra in Discharge Devices: the Influence of Reabsorption in Spectral Lines	1709
<i>Vladimir G. Novikov</i>	
Dynamical Orbital Collapse Drives Super Xe(M) X-Ray Emission at Lambda ~12-14 Å for Lithographic Applications	1725
<i>Charles Kirkham Rhodes</i>	
Influence of configuration interaction on satellite lines and on emission of EUV plasmas	1740
<i>Francois de Gaufridy de Dortan</i>	
Strongly Multiplexed Micro Plasma Pulse EUV Source with Non-Destructive EUV Radiation Collimating-Focusing Structure	1741
<i>Sergey Zakharov</i>	
The Development of EUV Resists Based on Non-polymeric Macromolecules with Polyphenol Derivatives	1762
<i>Masatoshi Echigo</i>	
Chemical Force Microscopy for Imaging Chemical Distributions in Undeveloped Resists	N/A
<i>John T. Woodward</i>	

Volume 4

UV Resist Tuning for EUV Application	1763
<i>Doohoon Goo</i>	
Development of Novel Resist Polymers for EUV Lithography	1781
<i>Takashi Sasaki</i>	
Distribution Control of Protecting Groups and its Effect on LER for EUV Molecular Resist	1790
<i>Daiju Shiono</i>	
Tools for EUV-Resist Characterization	1804
<i>Rainer Lebert</i>	
Chemically-Amplified Negative-Tone Molecular Resist using Polarity Change Reaction for EUVL	1814
<i>Kyoko Kojima</i>	
Resist Outgassing and Exposure Using the Energetiq EQ-10 Electrodeless Z-Pinch EUV Light Source	1831
<i>Paul A. Blackborow</i>	

Effect of Photoacid Generator Concentration on the Performance of a Model EUV Photoresist	1832
<i>Eric K. Lin</i>	
Evaluation of Molecular Glass Performance for 32nm Resolution and Beyond	1834
<i>Damien Djian</i>	
Comparison of EUV Resists Out-Gassing Under Continuous vs Pulsed Illumination	1835
<i>Julia Simon</i>	
Study of Extreme Ultra-Violet Photoresist Quality for 32nm Pattern Formation	1836
<i>Eun-Jin Kim</i>	
Anionic PAG Bound Photoresists for EUV	1848
<i>Mingxing Wang</i>	
Critical Issues of EUV Resists and New Research Approach	N/A
<i>S.Tagawa</i>	
Acid Generation in Chemically Amplified EUV Resists	1849
<i>T. Kozawa</i>	
Exposure Dose Dependence on LER of Latent Image in EB/EUV Lithographies Studied by Monte Carlo Technique	1866
<i>Akinori Saeki</i>	
Polymer Structure Dependence of Acid Generation in Chemically Amplified EUV Resists	1867
<i>Hiroki Yamamoto</i>	
Thermodynamic Analysis of Acid Amplifiers for EUV Lithography	N/A
<i>Robert Brainard</i>	
EUV Resists Limits - New Screening Results	1868
<i>Wolf-Dieter Domke</i>	
EUV Resist Outgassing Round Robin Results	1869
<i>Kim R. Dean</i>	
Novel Method to Quantify Resist Outgassing Induced Contamination Rates	N/A
<i>Annemieke van de Runstraat</i>	
Evaluation of EUV Scatterometry for CD Characterization of EUV Masks Using Rigorous FEM-Simulation	1896
<i>Frank Scholze</i>	
Etching Characteristics of Multi-Stack EUVL Mask Structure Using Inductively Coupled Plasma	N/A
<i>Moon-Soo Park</i>	
Fidelity of Rectangular Patterns Printed with 0.3-NA MET Optics	1897
<i>Yuusuke Tanaka</i>	
At Wavelength Measurements and Study of EUV Low Topology Phase Shift Masks	1917
<i>Marieke Richard</i>	
Development of Low Thermal Expansion Materials and CTE Measurement Tool for EUVL	1918
<i>Yasutomi Iwahashi</i>	
Improvements made to Corning ULE @ Glass to Meeting P-37 Specifications	1933
<i>William Rosch</i>	

Development of Low Defect Glass Substrate for EUVL	1934
<i>Mika Yokoyama</i>	
Effects of EUV Dry Etch Process on Image Placement (IP) Errors	N/A
<i>Hoon Kim</i>	
EUV Reflectometer for EUV Lithography	N/A
<i>Sung Yong Cho</i>	
EUV Absorber / Buffer Etch Variability Investigation	1946
<i>Pavel Nesladek</i>	
Evaluation of TaSix Absorber Stack with a Novel Buffer for EUVL Mask	1947
<i>Shinpei Tamura</i>	
Defect Repair of EUV Absorber Layer Using Low Acceleration Voltage FIB-GAE	1967
<i>Tsukasa Abe</i>	
Characteristics of Ru Capping and Optimization of EUV Mask Absorber Stack	1985
<i>Seung Yoon Lee</i>	
Development and Evaluation of EUV Mask Substrates	1986
<i>Shouji Shimojima</i>	
Flatness Response of an EUV Mask during Exposure Chucking	1992
<i>Madhura Nataraju</i>	
At-Wavelength Reflectometry with the EUV Tube	2012
<i>Andrew Egbert</i>	
Results from our Recently Delivered Automated Reflectometer for Measurement of Reflectivity of EUV Lithography Masks	2021
<i>Rupert C. Perera</i>	
Compact EUV Source and Optics System for Metrology and Material Interaction Studies	2022
<i>Christian Peth</i>	
At-Wavelength Evaluation of Multilayer Mirrors for EUV Lithography	2023
<i>Fumitaro Masaki</i>	
Precise and Compact EUV Reflectometer	2041
<i>Ulf Hinze</i>	
Design of Multilayer Mirrors for Metrology of EUV Sources	2042
<i>F. Bijkerk</i>	
AIXUV's Tools for EUV-Reflectometry	2043
<i>Christian Wies</i>	
Test Stand for Optical Characterization of Grazing Incidence Collectors	2052
<i>Klaus Bergmann</i>	
High Acceleration Test for Contamination of Ru Capping Layers for EUVL Projection Optics Mirrors	2053
<i>Yukinobu Kakutani</i>	
In situ XANES Analysis for EUVL Projection Optics Contamination	2070
<i>Masahito Niibe</i>	
Thermal- and Electron-Induced Reactions on the Ru(10-10) Surface: Relevance to Extreme Ultraviolet Lithography	2087
<i>Boris V. Yakshinskiy</i>	

Effect of Deposition, Sputtering, and Evaporation of Lithium Debris Buildup on EUV Optics	2088
<i>Martin Neumann</i>	
Gibbsian Segregating Alloys Driven by Thermal and Ion Flux Gradients	2089
<i>Huatan Qiu</i>	
Selective Etching of Sn from Ru EUV Mirrors with Ar/C12 Plasma	2090
<i>Hyungjoo Shin</i>	
Plasma Cleaning of Multilayer Coatings from Carbon and Tin Contaminations	2091
<i>Lopaev D.V.</i>	
Plasma-Assisted Electrostatic Cleaning of EUV Masks	2092
<i>Wayne M. Lytle</i>	
Study of Contamination of Mo/Si Multilayer Mirrors in Water and Hydrocarbon Environment under Controlled Vacuum Conditions	2093
<i>Rashi Garg</i>	
Effect of Current Processes on PRE, Damage, and Reflectance of EUV Mask	2094
<i>Jaehyuck Choi</i>	
Debris Mitigation and Cleaning for Sn-Fueled EUV Source	2111
<i>Takahiro Shirai</i>	
Managing the Vacuum Environment of a Source-Collector Module	2124
<i>Carolyn Hughes</i>	
Contamination Control in the Projection Optics Environment	2125
<i>Anthony Keen</i>	
Progress in the Optics Lifetime Programme for ASML EUV Lithographic Tools	N/A
<i>Bas Wolschrijn</i>	
Impact of Imaging Optics Quality on Actinic Mask Blank Inspection	2126
<i>Yoshihiro Tezuka</i>	
Imaging Characteristics of Dark-Field Actinic Mask Blank Inspection	2143
<i>Tsuneo Terasawa</i>	
EUV Microscopy for Defect Inspection	2161
<i>Larissa Juschkina</i>	
The Capability of Recent DUV Inspection and Printability for Pattern Defects on EUV Mask in 45nm Node and Below	2162
<i>Do Young Kim</i>	
Advanced Process for Mo-Si Multilayer Formation using an Assisted Ion Beam for EUVL Mask Blanks	2180
<i>Kenji Hiruma</i>	
Evaluation of Magnetron Sputter Deposition as Multilayer Coating Technology for EUVL Projection Optics	2198
<i>Stefan Braun</i>	
Dual Ion Beam Sputter Deposition for EUVL Optics: Large Area and High Reflectance	2199
<i>Stefan Braun</i>	
Wideband Multilayer Mirrors for EUV Optical Systems	2200
<i>E. Louis</i>	
Multilayer Coatings Development for Non-Radial Gradients on Aspherical Optics	2201
<i>Michael D. Kriese & Yuriy Y. Platonov</i>	

IBF Technology Development for EUVL Mirrors	2210
<i>Manabu Ando</i>	
Analysis of Relation between Resist LER and Optical Condition of Exposure Tool in EUV Lithography.....	2222
<i>Yukiko Kikuchi</i>	
Interface Engineering of Mo/Si Multilayers for Enhanced Reflectance in EUVL Applications.....	2246
<i>A.E. Yakshin</i>	
Characterization of Grazing Incidence Collectors Under Near Production Conditions	2247
<i>Klaus Bergmann</i>	
Ultra Low Thermal Expansion Material "CLEARCERAM®-Z" for EUVL Application	2248
<i>Yoshiyuki Owari</i>	
Demonstration of an EUV Phase-Only Computer-Generated Hologram.....	2249
<i>Patrick Naulleau</i>	
The Effect of Mask Background Density on Imaging Performance in EUV Lithography	2250
<i>Jinhong Park</i>	
Effect of Differential Pressure on Particle Contamination on EUVL Photomasks	2269
<i>Christof Asbach</i>	
Selete Mask Handling Program	2270
<i>Kazuya Ota</i>	
A Short-Pulsed Laser Cleaning System for EUVL Tool	2283
<i>Masami Yonekawa</i>	
Monitoring Optics Contamination	N/A
<i>M.H.L. van der Velden</i>	
Author Index	